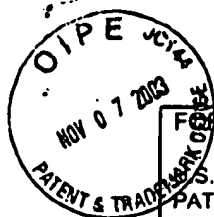


11/07/03



Sh et 1 of 1

FORM PTO-1449 (SUBSTITUTE) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))		Attorney Docket No.: MUH-12823	Applic. No. 10/685,064
		Applicant Peter Weitz	
		Filing Date October 14, 2003	Group Art Unit 2823

U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
K.N.	A	6,211,559 B1	04/03/03	Zhu et al.	257	421	02/27/98
	B						
	C						
	D						
	E						
	F						
	G						
	H						
	I						

FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
K.N.	J	1 061 592 A2	12/20/00	Europe			X
K.N.	K	99/14760	03/25/99	WIPO			X
	L						
	M						
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

K.N.	O	Roy E. Scheuerlein: "Magneto-Resistive IC Memory Limitations and Architecture Implications", <i>Proceedings of the 7th IEEE International Nonvolatile Memory Technology Conference</i> , June 22-24, 1998, pp. 47-50
K.N.	P	S. Tehrani et al.: "Recent Developments in Magnetic Tunnel Junction MRAM", <i>IEEE Transactions on Magnetics</i> , Vol. 36, No. 5, September 2000, pp. 2752-2757

EXAMINER <i>K. Baer</i>	DATE CONSIDERED 07/11/04
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	